Thank you for your interest in **onsemi** products.

Your technical document begins on the following pages.



Your Feedback is Important to Us!

Please take a moment to participate in our short survey.

At **onsemi**, we are dedicated to delivering technical content that best meets your needs.

Help Us Improve - Take the Survey

This survey is intended to collect your feedback, capture any issues you may encounter, and to provide improvements you would like to suggest.

We look forward to your feedback.

To learn more about **onsemi**, please visit our website at **www.onsemi.com**





Small Signal Diode 1N5282

(T_A = 25°C unless otherwise noted)

V_{RRM}	Maximum Repetitive Reverse Voltage	80	V
I _{F(AV)}	Average Rectified Forward Current	200	mA
I _{FSM}	Non–repetitive Peak Forward Surge Current Pulse Width = 1.0 s Pulse Width = 1.0 μ s	1.0 4.0	A A
T _{STG}	Storage Temperature Range	-65 to +200	°C
TJ	Operating Junction Temperature	175	°C

					ļ	V
V _F	Forward Voltage	$\begin{split} I_F &= 0.1 \text{ mA} \\ I_F &= 1.0 \text{ mA} \\ I_F &= 10 \text{ mA} \\ I_F &= 100 \text{ mA} \\ I_F &= 300 \text{ mA} \\ I_F &= 500 \text{ mA} \\ \end{split}$	0.45 0.55 0.67 0.80 0.92 1.05		0.49 0.60 0.725 0.90 1.1 1.3	V
I _R	Reverse Current	V _R = 55 V V _R = 55 V, T _A = 150°C	-	-	100 100	nA

© Semiconductor Components Industries, LLC, 2009

Publication Order Number:

AXIAL LEAD CASE 017AG ISSUE O

DATE 31 AUG 2016



